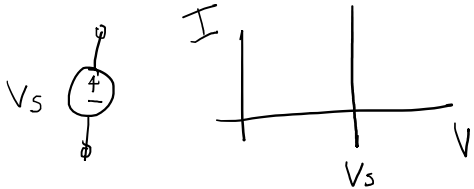


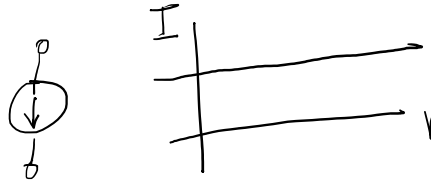
16A Review

(use w/ eqns in green box)
 (vocab underlined in blue)
 (edits after class from DH's chat questions in purple)

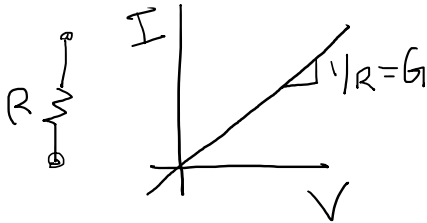
Voltage



Current



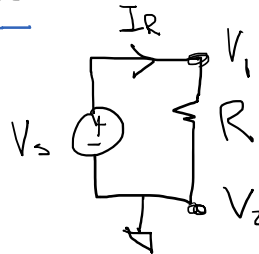
Resistor



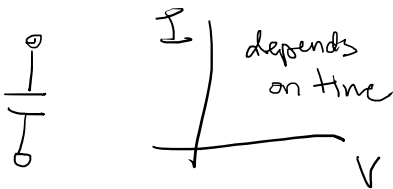
Ohm's Law

$$V_R = I_R R$$

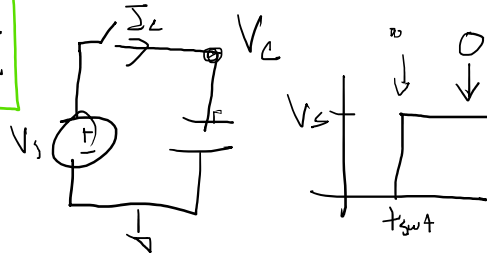
$$V_R = V_1 - V_2$$



Capacitor



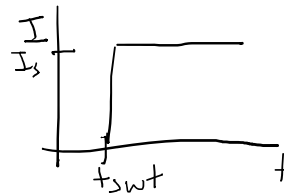
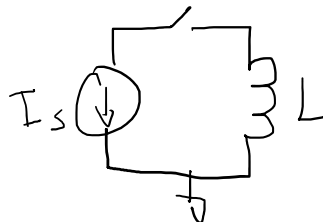
$$\frac{dV}{dt} C = I$$



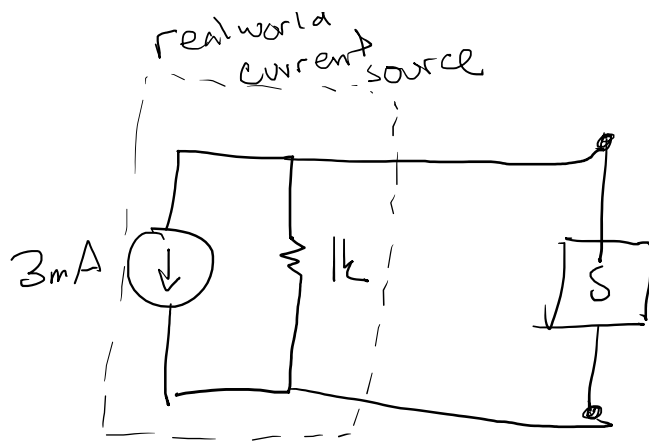
Inductor



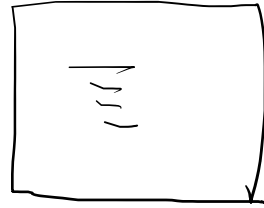
$$\frac{dI}{dt} L = V$$



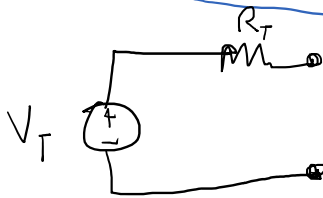
real world
 current source



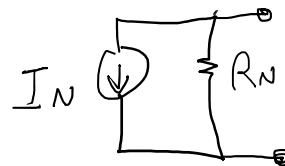
Data sheet



Thevenin

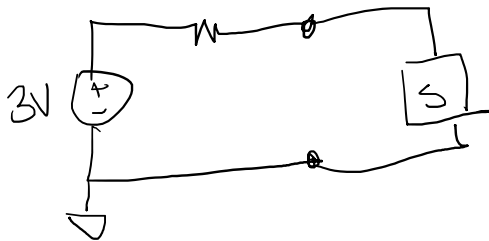


Norton



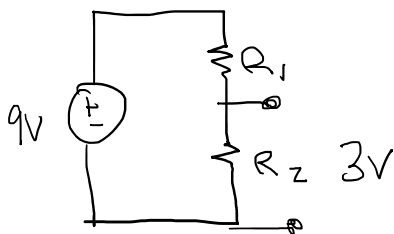
$$R_T = R_N$$

$$V_T = R_{T/N} I_N$$



9V

Voltage Divider



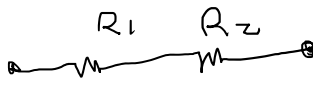
$$V_o = V_{in} \frac{R_2}{R_1 + R_2}$$

$$3V = 9V \frac{R_2}{R_1 + R_2}$$

$$\frac{R_1}{R_2} = \frac{2}{1} \quad \frac{2k}{1k}$$

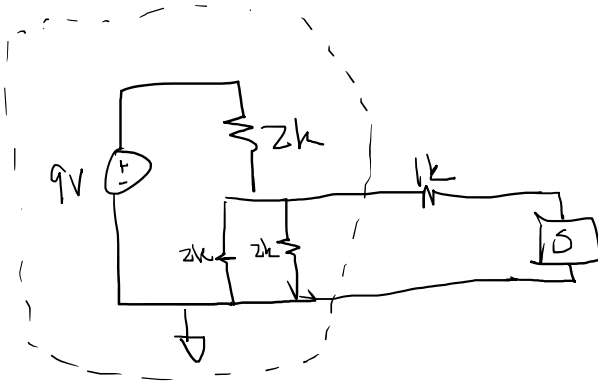
Resistor Equivalence

Series

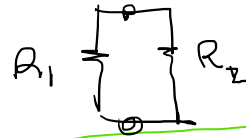


$$R_s = R_1 + R_2$$

Non-Ideal
3V source

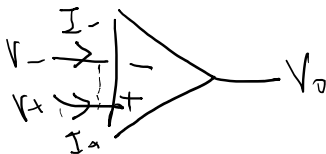


Parallel



$$R_p = \frac{1}{\frac{1}{R_1} + \frac{1}{R_2}} = \frac{R_1 R_2}{R_1 + R_2}$$

Opamps (!)



$$A_v = \frac{V_o}{V_{in}}$$

Idea: $A_v = \frac{3V}{9V}$

Golden Rules

(1) virtual short

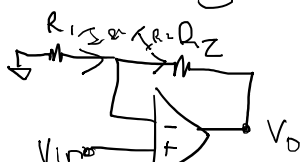
$$V_+ = V_-$$

($\frac{V}{I}$)

(2) infinite input impedance

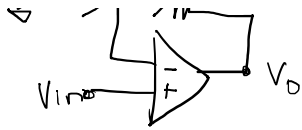
$$I_- = I_+ = 0$$

Non-Inverting Opamp



(1) $V_+ = V_- = V_{in}$

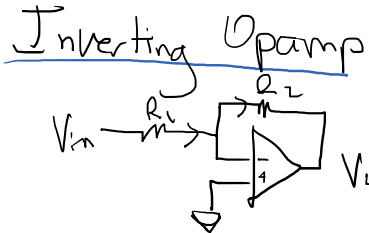
(2) $I_{R1} = I_{R2}$



$$(2) \quad I_{R1} = I_{R2}$$

$$\frac{0 - V_m}{R_1} = \frac{V_m - V_o}{R_2}$$

$$A_v = \frac{V_o}{V_{in}} = \frac{R_2}{R_1} + 1$$



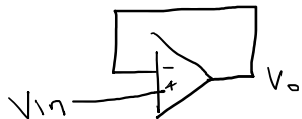
$$(1) \quad V_+ = V_- = 0$$

$$(2) \quad I_{R1} = I_{R2}$$

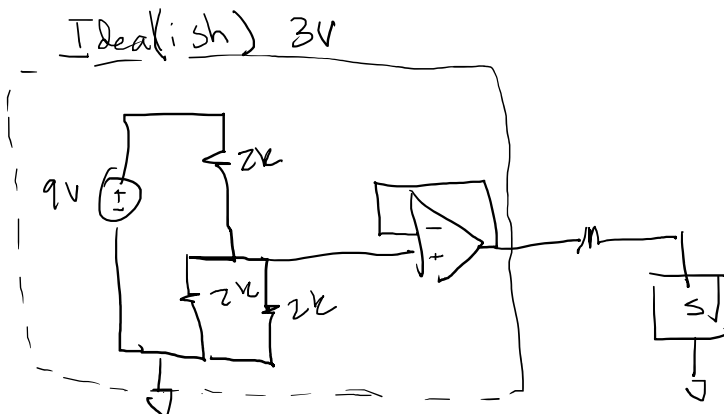
$$\frac{V_{in} - 0}{R_1} = \frac{0 - V_o}{R_2}$$

$$A_v = \frac{V_o}{V_{in}} = -\frac{R_2}{R_1}$$

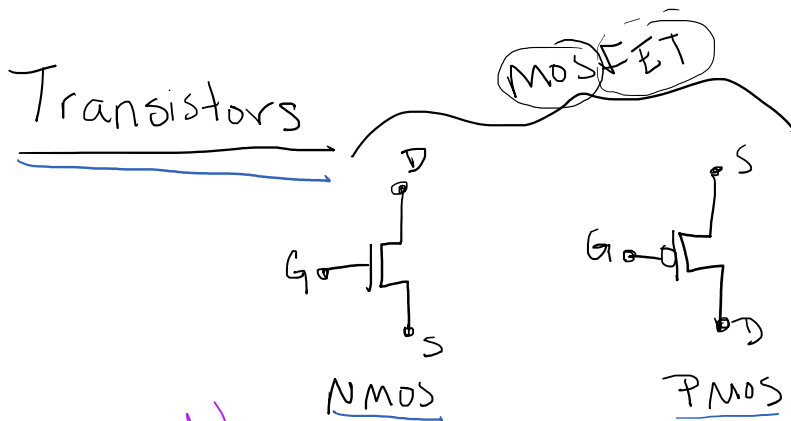
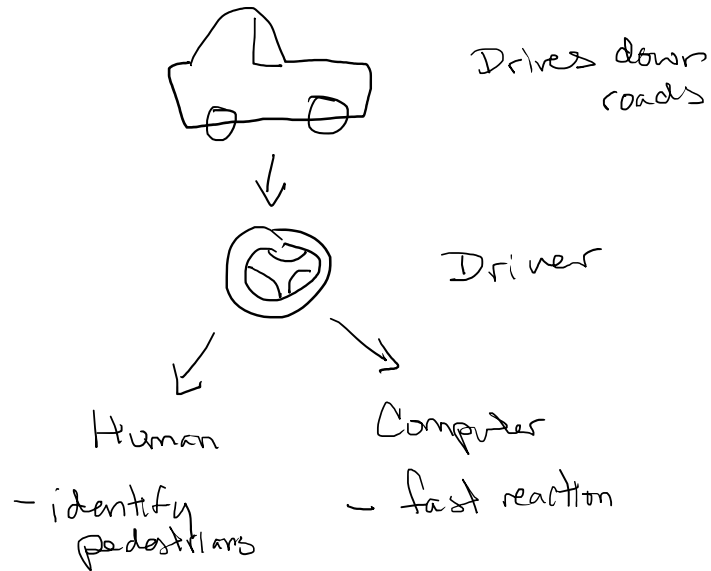
Buffer (Non-Inverting)



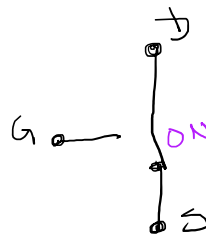
$$A_v = \frac{R_2}{R_1} + 1 = 1$$



Choosing the right model...



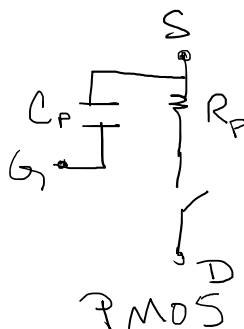
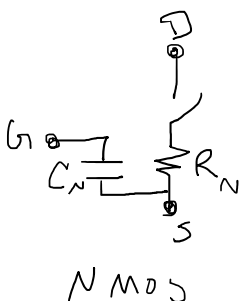
switch model
~~16 A~~



N
P

OFF	ON
$G = 0$	$G = 1$
$G = 1$	$G = 0$

1GB model

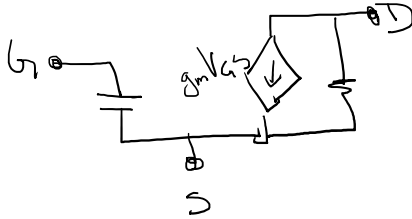


	OFF	ON
N	$G < V_{TH}$	$G > V_{TH}$
P	$G > V_{TH}$	$G < V_{TH}$

NMOS

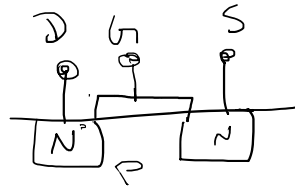
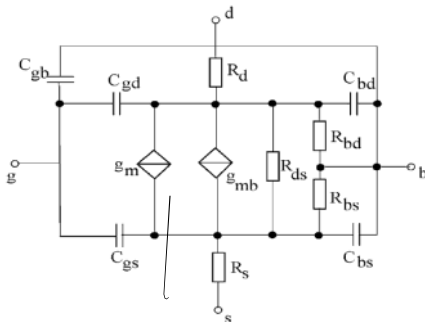
- Switch resistance
- gate capacitance
- threshold voltage

105 model



- analog V_{GS}
- current source

140 model



- details of analog

Simulation Model

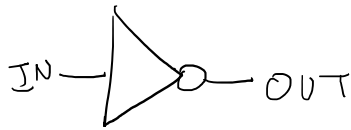
```
* PTH 130nm NMOS
.model2 nmos-B5DH130 nmos level = 54

+version = 4.0      binunit = 1      parametric 1      mcbmod = 0
+capmod = 2         igmod = 1        igmod = 1        gmodmod = 1
+diomod = 1         rdsmod = 0        rdsmod = 1        rgatmod = 1
+spmod = 1          acqmod = 0        trnsmod = 0

+tnom = 27          toxe = 2.25e-9   toxp = 1.6e-9     toxm = 2.25e-9
+dtot = 0.65e-9    epsrox = 3.9      wint = 5e-009     lint = 10.5e-009
+li = 0             ul = 0            lin = 1           uln = 1
+lu = 0             uu = 0            lun = 1           uun = 1
+lll = 0            uul = 0           xpart = 0         toxref = 2.25e-9
+ml = -60e-9
+vt0 = 0.3702      k1 = 0.4          k2 = 0.01         k3 = 0
+u0 = 0            u0 = 2.5e-006     dv0 = 1          dv1 = 2
+dv02 = -0.032     dv0u = 0          dv1u = 0          dv1u = 0
+dsu0 = 0.1        mlu = 0.05        voff1 = 0         voff2 = 1.2e-010
+dv0p1 = 0.1       lpu0 = 0          lpu0 = 0          xj = 3.92e-008
+ngate = 2e+020     ndop = 1.54e+018    nsd = 2e+020      pin = 0
+ncdsc = 0.0002    cdsd = 0             cdsd = 0          cit = 0
+nvoff = -0.15     nfactor = 1.5        wfab = 0.0002     etab = 0
+vf0 = -0.55       u0 = 0.05928        ua = 6e-010       ub = 1.2e-010
+uc = 0            vsat = 100370        a0 = 1            ags = 1e-020
+al = 0            al = 0             b0 = 0            b1 = 0
+aketa = 0.04      dug = 0             dub = 0           pc1e = 0.06
+pdibic1 = 0.001   pdibic2 = 0.001      pdibicb = -0.005  drout = 0.5
+prng = 1e+020     delta = 0.01         psich1 = 0.10e+008 psich2 = 1e+007
+fprount = 0.2     pdits = 0.00         pditsd = 0.23     pdits1 = 2.3e+006
+rrh = 5           rdsu = 200          rru = 100         rdu = 100
+rdsumin = 0       rdsumin = 0          rdsumin = 0       rdsumin = 0
+prub = 6.8e-011   ur = 1              alpha0 = 0.074    alpha1 = 0.005
+hrub = 0          asrlf = 0.0007     hrub = 0.7e+004   rrlf = 0.0007
```

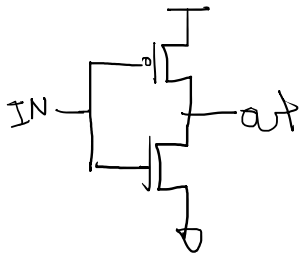
Integrated Circuit (IC)

Models in Practice : Inverter



IN	OUT
0	1
1	0

1 is any voltage $> V_{TH}$ (usually V_{DD})
 0 is any voltage $< V_{TH}$ (usually GND)

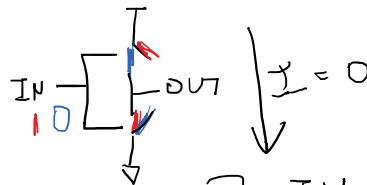


CPU Designer

- Power
- Heat
- Speed

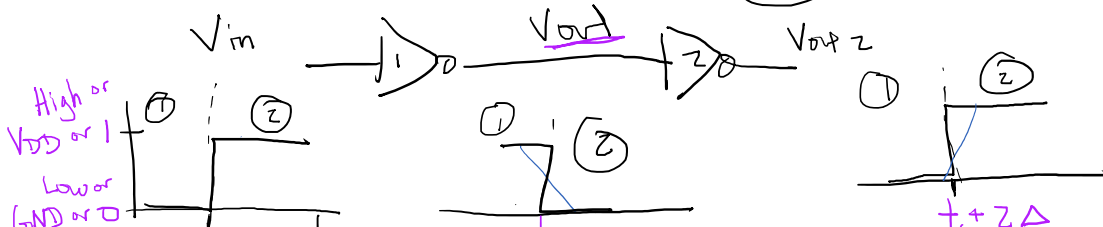
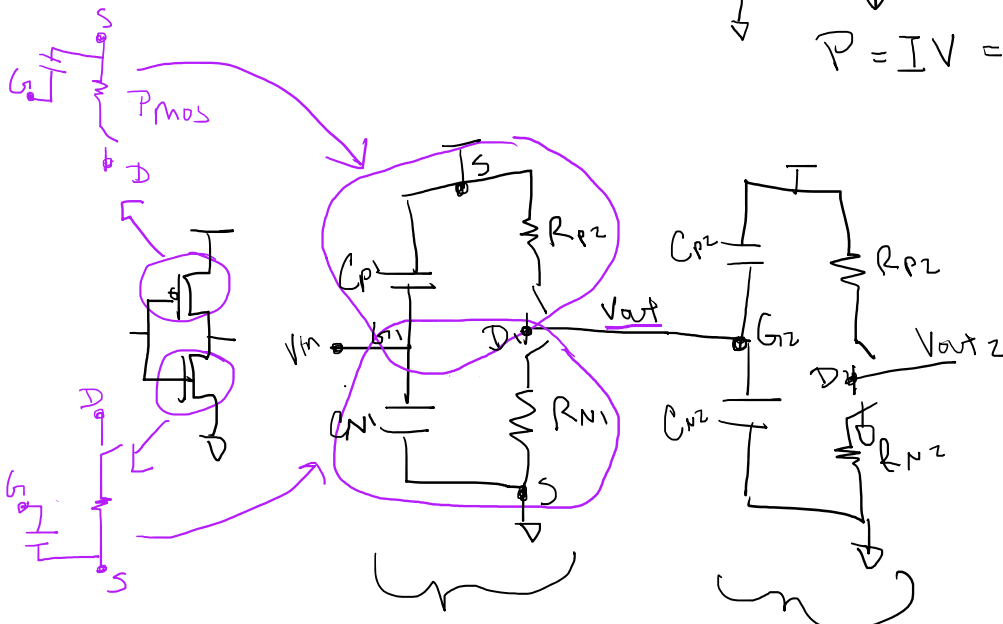
What's the Power?

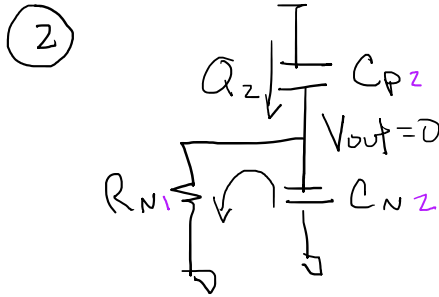
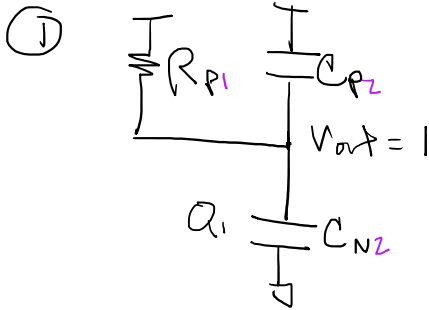
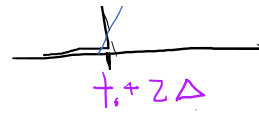
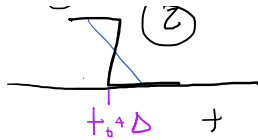
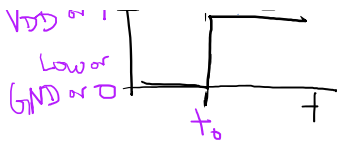
1G A model



$$P = IV = 0$$

Intuitively wrong, so switches only are a bad model





Useful eqns

$$E = P \cdot t = \frac{1}{2} Q V_c$$

$$Q = C V_c = \int I_c dt$$

①

$$Q_1 = C_N V_{out}$$

$$= C_N V_{DD}$$

②

$$Q_2 = C_P V_{out}$$

$$= C_P V_{DD}$$

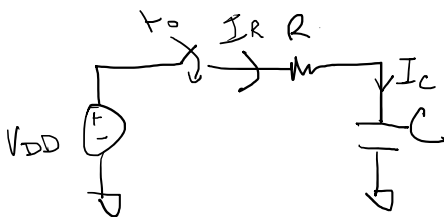
Power

$$P = \frac{E}{t} \leftarrow \text{speed?}$$

$$E = \frac{1}{2} Q V_{DD}$$

$$= \frac{1}{2} (C_{N/P} V_{DD}) V_{DD}$$

Charging a Cap in time



$$I_R(t) = I_C(t)$$

$$V_{DD} = V_R(t) + V_C(t)$$

We want to know how fast we can run our logic, so we need to know where the delay comes from.

Useful eqns

$$I_C(t) = C \frac{d}{dt} V_C(t)$$

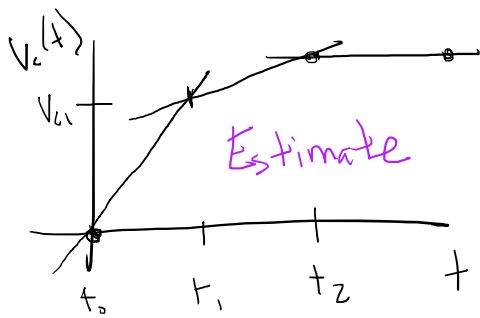
$$Q = C V_C(t) = \int I_C(t) dt$$

$$I_R(t) = \frac{V(t)}{R}$$

1. (x)



n



$$V_C(t) = \frac{1}{C} \int I_C(t) dt$$

$$I(t) = \frac{V_{DD} - V_C(t)}{R}$$

$$\textcircled{F_0} \quad V_C(t_0) = 0$$

$$I_R(t_0) = \frac{V_{DD}}{R}$$

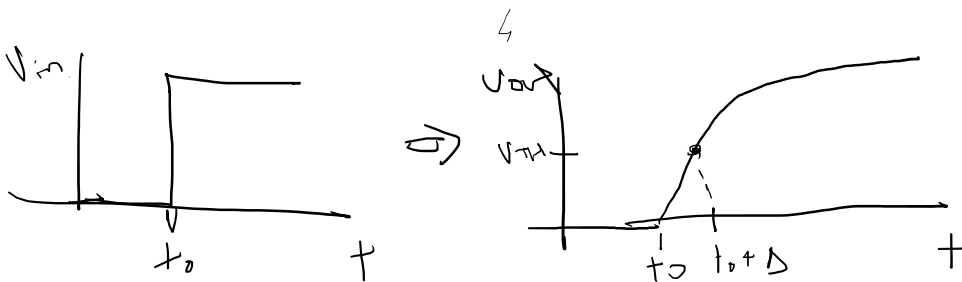
$$\textcircled{F_1}$$

$$V_C(t_1) = V_{C1}$$

$$> \quad I_R(t_1) = \frac{V_{DD} - V_{C1}}{R}$$

Intuition: Capacitors charge slower the more charge on them

$I_C(t) \downarrow$ as $V_C(t) \uparrow$ for const V_S



What do w/ Δt ?

How math Δt ?

